Power MOSFET

7.0 A, 20 V, Common Drain, Dual N–Channel, TSSOP–8

Features

- Low R_{DS(on)}
- Higher Efficiency Extending Battery Life
- Logic Level Gate Drive
- 3 mm Wide TSSOP-8 Surface Mount Package
- High Speed, Soft Recovery Diode
- TSSOP-8 Mounting Information Provided
- Pb–Free Package is Available

Applications

• Battery Protection Circuits

MAXIMUM RATINGS ($T_C = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	20	Vdc
Gate-to-Source Voltage - Continuous	V _{GS}	±12	Vdc
Drain Current – Continuous @ T _A 25°C (Note 1) – Continuous @ T _A 70°C (Note 1) – Pulsed (Note 3)	I _D I _D I _{DM}	7.0 5.6 20	Adc
Total Power Dissipation @ T _A 25°C (Note 1)	PD	1.81	W
Drain Current – Continuous @ T _A 25°C (Note 2) – Continuous @ T _A 70°C (Note 2) – Pulsed (Note 3)	I _D ID I _{DM}	6.2 4.9 18	Adc
Total Power Dissipation @ T _A 25°C (Note 2)	PD	1.39	W
Operating and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C
Thermal Resistance – Junction–to–Ambient (Note 1) Junction–to–Ambient (Note 2)	$R_{\theta JA}$	69 90	°C/W
Maximum Lead Temperature for Soldering Purposes for 10 seconds	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

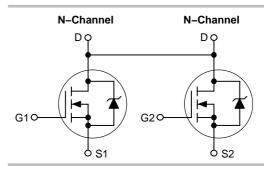
- 1. Mounted onto a 2" square FR-4 Board
- (1 in sq, 2 oz. Cu 0.06'' thick single sided), t \leq 10 sec. 2. Mounted onto a 2'' square FR-4 Board
- (1 in sq, 2 oz. Cu 0.06" thick single sided), Steady State.
- 3. Pulse Test: Pulse Width = $300 \,\mu$ s, Duty Cycle = 2%.



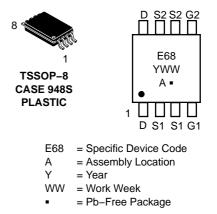
ON Semiconductor®

http://onsemi.com

V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
20 V	17 mΩ @ 4.5 V	7.0 A



MARKING DIAGRAM & PIN ASSIGNMENT



ORDERING INFORMATION

Device	Package	Shipping [†]
NTQD6968N	TSSOP-8	100 Units / Rail
NTQD6968NR2	TSSOP-8	4000/Tape & Reel
NTQD6968NR2G	TSSOP-8 (Pb-Free)	4000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_C = 25° C unless otherwise noted)

Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage ($V_{GS} = 0 \text{ Vdc}, I_D = 250 \mu \text{Adc}$) Temperature Coefficient (Positive)			20 -	_ 16		Vdc mV/°C
Zero Gate Voltage Collector Current $(V_{DS} = 16 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J =$ $(V_{DS} = 16 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J =$	= 25°C) = 125°C)	I _{DSS}			1.0 10	μAdc
Gate–Body Leakage Current ($V_{GS} = \pm 12 \text{ Vdc}, V_{DS} = 0 \text{ Vdc}$)		I _{GSS}	_	_	±100	nAdc
ON CHARACTERISTICS					•	
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250 \mu Adc$) Temperature Coefficient (Negative)		V _{GS(th)}	0.6	0.75 3.0	1.2 -	Vdc mV/°C
Static Drain-to-Source On-State Resistance ($V_{GS} = 4.5 \text{ Vdc}, I_D = 7.0 \text{ Adc}$) ($V_{GS} = 2.5 \text{ Vdc}, I_D = 7.0 \text{ Adc}$) ($V_{GS} = 2.5 \text{ Vdc}, I_D = 3.5 \text{ Adc}$)		R _{DS(on)}	- - -	0.017 0.022 0.022	0.022 0.030 0.030	Ω
Forward Transconductance (V_{DS} = 10 Vdc, I_D = 7.0 Adc)		9FS	_	19.2	-	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	630	-	pF
Output Capacitance	$(V_{DS} = 16 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{oss}	-	260	-	
Transfer Capacitance	- ,	C _{rss}	-	95	-	
SWITCHING CHARACTERISTICS (Notes 4 and 5)					
Turn-On Delay Time		t _{d(on)}	-	8.0	-	ns
Rise Time	(V _{DD} = 16 Vdc, I _D = 7.0 Adc,	t _r	-	25	-	
Turn-Off Delay Time	$V_{GS} = 4.5 \text{ Vdc}, R_G = 6.0 \Omega$	t _{d(off)}	-	60	-	
Fall Time		t _f	-	65	-	
Gate Charge	$()/_{} = 16)/dc$	Q _{tot}	_	12.5	17	nC
	(V _{DS} = 16 Vdc, V _{GS} = 4.5 Vdc,	Q _{gs}	_	1.0	-	
	I _D = 7.0 Adc)	Q _{gd}	_	5.0	-	
BODY-DRAIN DIODE RATINGS (N	ote 4)					
Forward On–Voltage	$(I_{S} = 7.0 \text{ Adc}, V_{GS} = 0 \text{ Vdc})$	V _{SD}	-	0.82	1.2	Vdc
Reverse Recovery Time		t _{rr}	-	35	-	ns
	$ (I_S = 7.0 \text{ Adc}, \text{V}_{GS} = 0 \text{Vdc}, \\ dI_S/\text{dt} = 100 \text{A}/\mu\text{s}) $	ta	-	15	-	
		t.	_	20	_	7

Reverse Recovery Stored Charge

Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%.
 Switching characteristics are independent of operating junction temperature.

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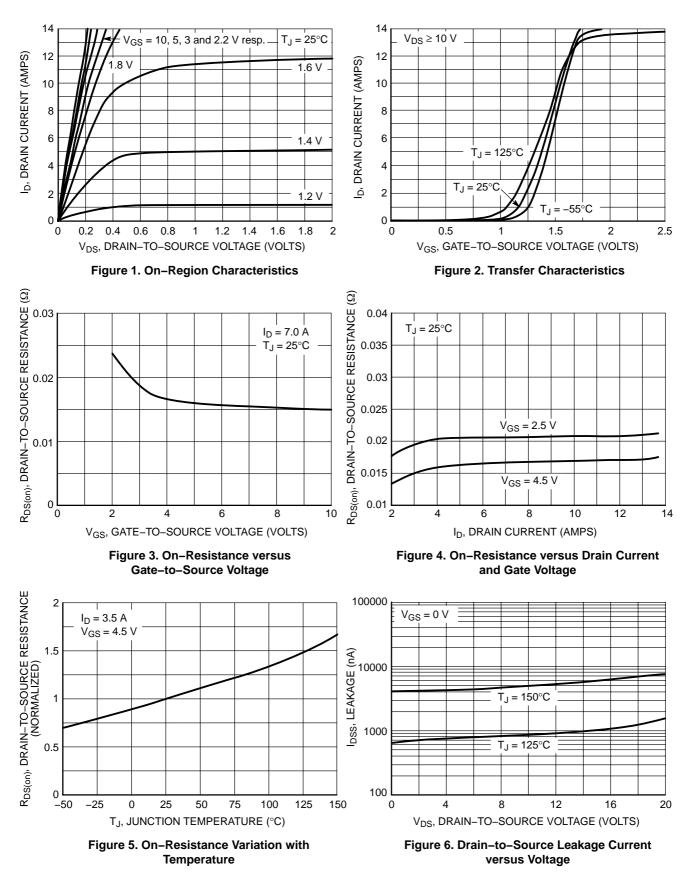
μC

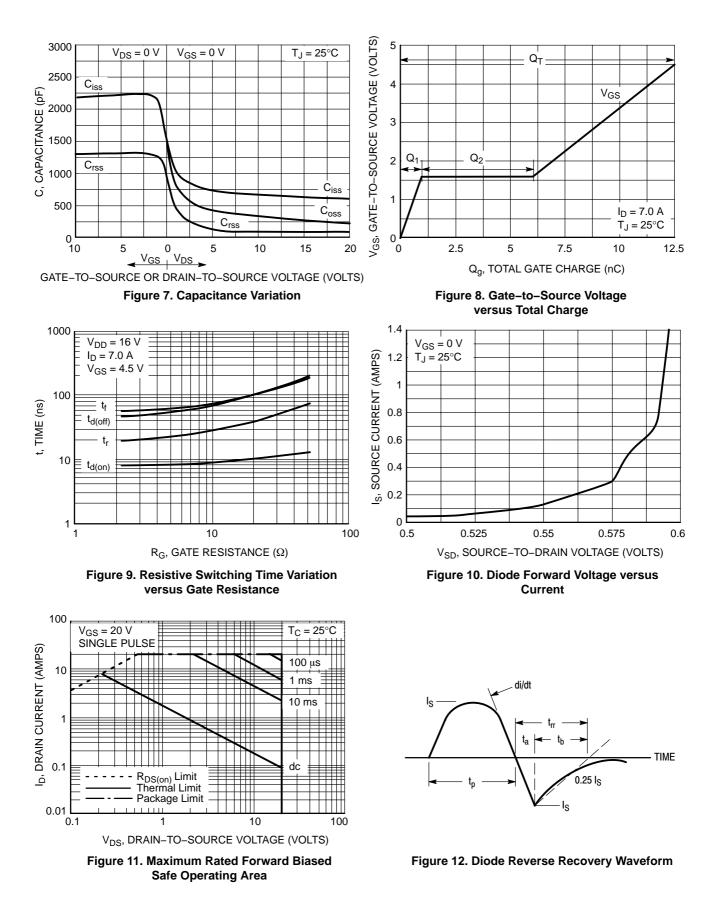
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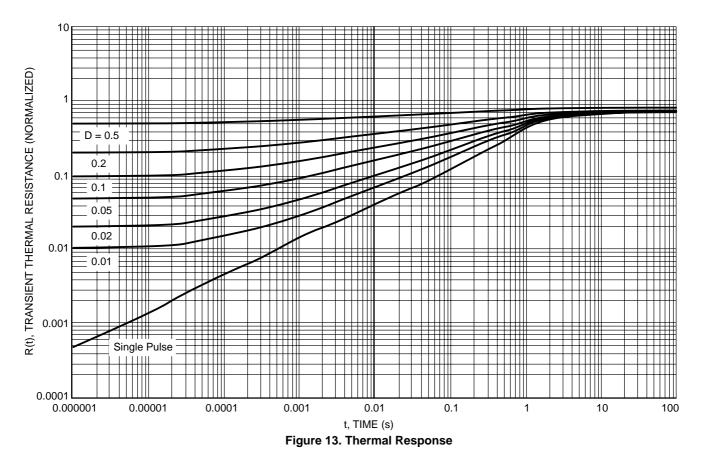
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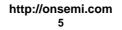
tb

Q_{RR}







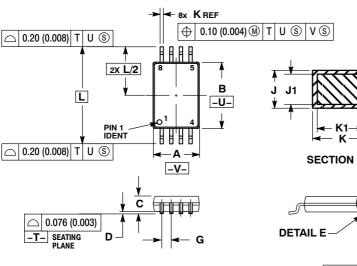


SCALE 2:1

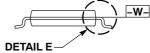


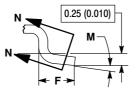
TSSOP-8 CASE 948S-01 ISSUE C

DATE 20 JUN 2008



SECTION N-N





DETAIL E

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

- VIMENSIONING AND TOLENANDING FER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH.
- PROTRUSIONS OF GATE BURNS. MOLD PLASH OR GATE BURNS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) DED SUDE PER SIDE
- 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.114	0.122	
В	4.30	4.50	0.169	0.177	
С		1.10		0.043	
D	0.05	0.15	0.002	0.006	
F	0.50	0.70	0.020	0.028	
G	0.65 BSC		0.026 BSC		
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.19	0.30	0.007	0.012	
K1	0.19	0.25	0.007	0.010	
L	6.40	6.40 BSC		0.252 BSC	
М	0°	8°	0°	8°	

GENERIC **MARKING DIAGRAM***

S	XXX YWW	
	A •	
	•	

XXX = Specific Device Code А

- = Assembly Location
- = Year

Y

- WW = Work Week
- = Pb-Free Package -

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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100115		DATE
ISSUE	REVISION	DATE
0	RELEASED FOR PRODUCTION.	18 APR 2000
А	ADDED MARKING DIAGRAM INFORMATION. REQ. BY V. BASS.	13 JAN 2006
В	CORRECTED MARKING DIAGRAM PIN 1 LOCATION AND MARKING. REQ. BY C. REBELLO.	13 MAR 2006
С	REMOVED EXPOSED PAD VIEW AND DIMENSIONS P AND P1. CORRECTED MARKING INFORMATION. REQ. BY C. REBELLO.	20 JUN 2008

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